## NSN 5961-00-813-9029

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**Demilitarization:** 

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-813-9029 **Inclosure Material:** Metal **Overall Length:** 0.520 inches **Overall Diameter:** 1.250 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 collector to emitter voltage, dc and -5.0 emitter to base voltage, dc **Power Rating Per Characteristic:** 150.0 watts total power dissipation **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 18876-mis17247 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure:**